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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Tetsuzo UEDA, et al.

Application No.: 10/812,416

Filed: March 30, 2004



: Response Under 37 CFR 1.116 - Expedited Procedure
: Customer Number: 53080
: Confirmation Number: 1264
: Group Art Unit: 2811
: Examiner: Crane, Sara W.

For: A 4H-POLYTYPE GALLIUM NITRIDE-BASED SEMICONDUCTOR DEVICE ON A 4H-POLYTYPE SUBSTRATE

Mail Stop AF
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

Transmitted herewith is an Amendment Under 37 CFR 1.116 in the above-identified application.

- No additional fee is required.
- Applicant is entitled to small entity status under 37 CFR 1.27
- Also attached:

The fee has been calculated as shown below:

	NO. OF CLAIMS	HIGHEST PREVIOUSLY PAID FOR	EXTRA CLAIMS	RATE	FEE
Total Claims	4	49	0	\$50.00 =	\$0.00
Independent Claims	1	5	0	\$200.00 =	\$0.00
Multiple dependent claims newly presented					\$0.00
Fee for extension of time					\$0.00
					\$0.00
Total of Above Calculations					\$0.00

- Please charge my Deposit Account No. 500417 in the amount of \$0.00. An additional copy of this transmittal sheet is submitted herewith.
- The Commissioner is hereby authorized to charge payment of any fees associated with this communication or credit any overpayment, to Deposit Account No. 500417, including any filing fees under 37 CFR 1.16 for presentation of extra claims and any patent application processing fees under 37 CFR 1.17.

Respectfully submitted,

McDERMOTT WILL & EMERY LLP

Michael E. Fogarty
Registration No. 36,139

Please recognize our Customer No. 53080 as our correspondence address.

600 13th Street, N.W.
Washington, DC 20005-3096
Phone: 202.756.8000 MEF:kap
Facsimile: 202.756.8087
Date: January 22, 2007



Docket No.: 074968-0011

PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Tetsuzo UEDA, et al.

RESPONSE UNDER 37 CFR 1.116
EXPEDITED PROCEDURE

Application No.: 10/812,416

Customer No.: 53080
Confirmation No.: 1264

Filed: March 30, 2004

Group Art Unit: 2811

Examiner: Crane, Sara W.

Title: A 4H-POLYTYPE GALLIUM NITRIDE-BASED SEMICONDUCTOR DEVICE ON
A 4H-POLYTYPE SUBSTRATE

AMENDMENT UNDER 37 CFR 1.116

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P.O. Box 1450
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Sir:

In response to the Final Office Action dated October 20, 2006, having a three-month shortened statutory period for response set to expire January 20, 2007, please amend the above identified application as follows: